Molecular Dynamics Simulations of Silicon Carbide, Boron Nitride and Silicon for Ceramic Matrix Composite Applications

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Abstract

A comprehensive computational molecular dynamics study is presented for crystalline $\alpha$-SiC (6H, 4H, and 2H SiC), $\beta$-SiC (3C SiC), layered boron nitride, amorphous boron nitride and silicon, the constituent materials for high-temperature SiC/SiC compositions. Large-scale Atomic/Molecular Parallel Simulator software package was used. The Tersoff Potential force field was utilized to evaluate their mechanical characteristics of most of the materials, and the Reax force field was used to model silicon when the Tersoff Potential did not provide accurate results. Their mechanical behaviors were evaluated at a strain rate of $10^7$/s, and the results agree with the experimental data in the literature. The results are foundational for linking constituent behavior to composite performance, particularly when test data is unavailable or suspect.

Introduction

A ceramic matrix composite (CMC) can be generally described as a material system comprised of fibers or particles embedded within a ceramic matrix. For example, silicon carbide/silicon carbide (SiC/SiC) composites contain coated SiC fibers and a SiC matrix. Of particular interest for high temperature applications are SiC/SiC CMCs that utilize a fiber coating composed of boron nitride (BN) (Refs. 1 to 3).

Within a SiC/SiC CMCs, SiC can exist in several crystalline phases including $\alpha$-SiC (6H, 4H, and 2H SiC), $\beta$-SiC (3C) and as an amorphous material ($\alpha$-SiC) (Refs. 4 to 7). The BN coating contains amorphous BN (a-BN) with a small volume fraction of layered hexagonal BN (h-BN) (Refs. 8 and 9). Finally, some unreacted silicon (Si) from processing exists in a crystalline (c-Si) or amorphous structure ($\alpha$-Si). The molecular structure of the phases within the fiber, matrix, and coating influence the thermo-mechanical behavior of the composite and can be controlled through a combination of material processing methods including chemical vapor infiltration, melt infiltration, and polymer impregnation and pyrolysis (Refs. 10 and 11).

Because of flexibility in the arrangement of the different phases within a given constituent, in addition to the morphology of the constituents (fibers and coating within the matrix) themselves, it may be possible to design SiC/SiC composites to meet specific performance requirements. Validated numerical simulations can be utilized during the material design process, effectively widening the available design space and allowing for exploration of novel microstructures at a relatively low expense and rapid throughput compared to physical material production and testing. To achieve this, accurate data for the thermo-mechanical properties of the basic phases of the constituent materials in the composite must first be obtained through experimentation or simulation.

Bosak et al. (Ref. 12) determined five independent elastic moduli of single-crystal hexagonal boron nitride (h-BN) using inelastic x-ray scattering. Their results provide solid foundation for further
theoretical advances and quantitative input to models including BN nanotubes. Kamitani et al. (Ref. 13) determined the elastic constants of 4H and 6H SiC single crystals by Brillouin scattering. Harris (Ref. 14) determined the elastic moduli of β-SiC. Pozzi et al. (Ref. 15) determined the mechanical properties of a 3C-SiC film using cantilevers and bridges in SiC. Zhi et al. (Ref. 16) fabricated ultrathin boron nitride nanosheets, and detailed morphological and structural microscopic studies were performed. They found that polymeric composites containing BN nanosheets exhibited a significant reduction of the coefficient of thermal expansion (CTE) and possessed enhanced elastic modulus and strength. Jackson et al. (Ref. 17) measured the elastic modulus, strength, and Poisson’s ratio of two different silicon carbides and detailed the techniques utilized to obtain these results.

Li et al. (Ref. 18) studied the effect of amorphous carbon coatings on the mechanical behavior of SiC nanowires via molecular dynamics methods at room temperature. Their results showed that amorphous carbon coatings can shield opening cracks in nanowires, making them damage-tolerant. Crocombette et al. (Ref. 19) performed nonequilibrium molecular dynamics (MD) modeling to determine the thermal conductivity of irradiated SiC as a function of cascade overlap using a Tersoff type empirical potential. Their calculated dependence of conductivity on irradiation dose was consistent with the experimental measurements of conductivity at low temperature irradiation. Zhao and Xue (Ref. 20) performed MD simulations to investigate the mechanical properties of hybrid graphene and h-BN sheet with the concentration of BN ranging from 0 to 100 percent. They showed that the Young’s modulus of the hybrid sheet decreased with increasing concentration of BN, irrespective of BN shapes and distributions. Natsuki et al. (Ref. 21) predicted the elastic properties of BN nanosheets using a molecular mechanics model and the simulated result shows that BN nanosheets exhibit an isotropic elastic material behavior. Some authors (Refs. 22 to 26) also investigated the mechanical and electronic properties of h-BN nanosheets using density functional theory (DFT) calculations and achieved good agreement with existing experimental data available in the open literature.

The focus of the current work is to develop foundational atomic scale models for the different phases, SiC, BN, and Si, that appear within a SiC/SiC CMC. This is preliminary work towards establishing a multiscale modeling framework to enable a link between the molecular structure of the materials phases, the arrangement of the phases in the constituents, and the morphology of the constituents in the composite to the performance of the composite material. Measuring the properties at such a small length scale is challenging and costly. Moreover, experimental data at this scale may contain some unquantified error, and computational modeling can be used to verify experimental results and conclusions. Thus, the first step in the advancement of the multiscale framework is to establish and validate MD simulations to predict the mechanical properties of the different possible material phases in a SiC/SiC composite. In this study, MD models of α-SiC (6H, 4H, and 2H SiC), β-SiC (3C), amorphous BN (a-BN), h-BN, and crystalline Si were generated using Large-scale Atomic/Molecular Massively Parallel Simulator (LAMMPS) in order to predict their elastic properties. Data from these models were compared to experimental results, where available. Furthermore, three realizations for each material system were independently developed and evaluated to compute average properties in order to remove some level of uncertainty related to the stochastic nature of the simulated data.

**The Modeling of Micro Constituents**

**Modeling and Simulation of Crystalline SiC and Layered BN**

The crystalline SiC polytypes (α and β structures) and h-BN were constructed, as shown in Figure 1 to Figure 5, using the LAMMPS package with Tersoff potentials. This potential is chosen because it is computationally efficient. At first, the primitive cells with periodic boundary conditions for all structures were constructed. Then, the supercell crystalline model of each structure was created by replicating the primitive cell in the X-, Y-, and Z-directions. Specifically, the α-SiC (6H-, 4H-, and 2H-SiC) structure was modeled using the primitive vectors given by Reference 17.
Figure 1.—6H SiC primitive cell (left) and a supercell (right) of size $10 \times 10 \times 10$ (23,040 atoms).

Figure 2.—4H SiC primitive cell (left) and a supercell (right) of size $10 \times 10 \times 10$ (16,000 atoms).
Figure 3.—Wurtzite SiC (2H) primitive cell (left) and a supercell (right) of size $17 \times 10 \times 10$ (13,200 atoms).

Figure 4.—$\beta$-SiC (3C) primitive cell (left) and a supercell (right) of size $15 \times 15 \times 15$ (2,471 atoms).

Figure 5.—Bilayer h-BN primitive cell (left) and a supercell (right) of size $20 \times 20 \times 1$ (3,192 atoms).
\begin{align}
a_1 &= \frac{1}{2}a_i - \frac{\sqrt{3}}{2}a_j \\
a_2 &= \frac{1}{2}a_i + \frac{\sqrt{3}}{2}a_j \\
a_3 &= ck
\end{align}

where, \(a = 3.08129\,\text{Å}\) and \(c/a = 4.90695780014\) for 6H SiC and \(a = 3.08051\,\text{Å}\) and \(c/a = 3.27374363336\) for 4H SiC. The primitive cells and supercells for 6H-SiC and 4H-SiC are shown in Figure 1 and Figure 2, respectively. Equation (1) also describes the primitive vector for the wurtzite 2H SiC structure. The primitive cell and an \(11\times7\times7\) supercell are shown in Figure 3. The 2H SiC structure is described with \(a = 3.072\,\text{Å}\) and \(c = 5.041152\,\text{Å}\) (Ref. 4).

The \(\beta\)-SiC (3C) was constructed with primitive vectors expressed as

\begin{align}
a_1 &= \frac{1}{2}a_j - \frac{1}{2}a_k \\
a_2 &= \frac{1}{2}a_i + \frac{1}{2}a_k \\
a_3 &= \frac{1}{2}a_i + \frac{1}{2}a_j
\end{align}

where \(a = 4.3596\,\text{Å}\). The primitive cell and supercell for \(\beta\)-SiC (3C) structure are shown in Figure 4.

The structure for bilayer h-BN was modeled using the primitive vectors given by Reference 6

\begin{align}
a_1 &= \frac{\sqrt{3}}{2}a_i - \frac{1}{2}a_j \\
a_2 &= \frac{\sqrt{3}}{2}a_i + \frac{1}{2}a_j \\
a_3 &= ck
\end{align}

where \(a = 2.50399\,\text{Å}\) and \(c = 6.6612\,\text{Å}\). Both the unit cell and supercell are shown in Figure 5.

Then, MD simulations were performed using the NVT (constant number of atoms, volume, and temperature) ensemble at 300 K for 100 ps in order to relax the structures. Minimization was performed over 100 ps at a temperature of 300 K using the conjugate gradient stopping criterion to further reduce the internal forces and residual stresses that were created from the initial construction of the bonds and the bond angles. After the initial relaxation process was completed, the final equilibration of the system was done under the NPT ensemble at 300 K for 1000 ps using a time step of 0.08 fs and Nose-Hoover barostat and thermostat.
The amorphous form of boron nitride (a-BN) is the dominant phase in most BN coatings (Refs. 8 and 9). The properties, and directionality of h-BN and a-BN are disparate. Thus, by changing the amount of h-BN within an a-BN matrix, it is possible to tailor its microstructural and mechanical properties to meet engineering needs. The development of computational material modeling to understand atomistic structure of a-BN, in conjunction with h-BN, has an important impact as this allows engineers not to only predict materials properties but also design materials for specific applications.

For this reason, a-BN models were prepared from crystalized h-BN models using a heating and cooling process. First, the h-BN was gradually heated in the NPT ensemble to a temperature of 6000 K. In reality, h-BN melting temperature is about 3,400 K (Ref. 27). In MD simulations, high temperature is used to reduce the computational time. Heating at high temperature for sufficient time melts the h-BN model by completely removing the memory of the initial crystalline configuration. Then the amorphous structure was simulated for 200 ps in the NPT ensemble before it was subjected to cooling to room temperature under the NVT ensemble at a quenching rate 100 K/ps. This nonequilibrium cooling establishes the formation of amorphous structure after solidification. The material system was finally equilibrated in NPT ensemble at 300 K for 200 ps before being evaluating its mechanical properties. In this study, two, four, five, and ten layers of h-BN were utilized for the development of amorphous structures in order to assess the influence of number of layers on predicted properties. As an example, the amorphous structure resulting from the heating and quenching of four and two h-BN layers, respectively, is shown in Figure 6. It is important to note that different cooling rates have been used in the literature ranging from 0.5 to 100 K/ps for different ceramic composites such as SiC and glass (Refs. 28 and 29). The upper limit (100 K/ps) was selected to model BN for high amorphous content in this study.

Modeling and Simulation of Crystalline Silicon

A crystalline Si model was constructed using the LAMMPS package with Reactive force field (ReaxFF) potentials from the primitive vectors expressed as:

\[ a_1 = \frac{1}{2} a_j - \frac{1}{2} a_k \]  \hspace{1cm} (4a)

\[ a_2 = \frac{1}{2} a_i + \frac{1}{2} a_k \]  \hspace{1cm} (4b)

\[ a_3 = \frac{1}{2} a_i + \frac{1}{2} a_j \]  \hspace{1cm} (4c)

where \( a = 5.43070 \) Å. ReaxFF was chosen in lieu of the Tersoff Potential for Si because it provides superior accuracy for Si, but at an added computational expense. The primitive cell and supercell for silicon utilized in this study are shown in Figure 7.
Figure 7.—The primitive cell (left) and supercell (right) of size $20 \times 20 \times 20$ for silicon comprises 7,531 atoms.

ReaxFF was utilized for evaluating the properties of silicon because the Tersoff potential elastic property results showed a significant deviation from available experimental data. Then, MD simulations were performed using the NVT ensemble at 300 K for 100 ps in order to relax the structures. Minimization was performed at a temperature of 300 K using the conjugate gradient stopping criterion. After the initial relaxation process was completed, the final equilibration of the system was performed under the NPT ensemble at 300 K for 500 ps using a time step of 0.08 fs and Nose-Hoover barostat and thermostat.

Calculating Elastic Properties Using Molecular Dynamics

The equilibrated structure was mechanically deformed to obtain the required stress-strain relationship for evaluating the elastic constants. A distinct displacement vector was imposed to determine each elastic constant. For the case of elastic moduli, an axial strain is applied on the periodic models using the “fix deform” command in LAMMPS under the NPH (constant number of atoms, pressure, and enthalpy) ensemble at one atmosphere and a temperature of 300 K. This allows the Poisson’s effect on two orthogonal directions to be calculated. The corresponding stress component in the axial direction was determined for a complete stress-strain response. NPH simulations were run for 1000 ps with time steps of 0.08 fs. The displacement was applied incrementally at every time step in such a way that the desired strain magnitude of 0.01 was attained at the end of 1000 ps. From each time step, the overall elastic modulus of the model (in the loading direction) was obtained from the plot of the stress-strain curve.

To obtain the stress-strain curve during the tensile loading, the virial stress $\sigma_{\alpha\beta}$ (Refs. 20 and 30) was computed from the equation

$$\sigma_{\alpha\beta} = \frac{1}{V} \left( \sum_{i=1}^{N} m v_{i\alpha} v_{i\beta} + \frac{1}{2} \sum_{i=1}^{N-1} \sum_{j=i+1}^{N} r_{ij,\alpha} F_{ij,\beta} \right)$$

(5)

where $V$ is the total volume of the material system used in the simulation cell, $\alpha$ and $\beta$ are the indices in the Cartesian coordinate system, $m$ and $v_{i\alpha}$ denote the mass and $\alpha$-component velocity of the atom $i$, $r_{ij,\alpha}$ and $F_{ij,\beta}$ denote the $\alpha$-component of the separation and the $\beta$-component of the force between atoms $i$ and $j$, respectively. The cumulative magnitude of the applied strain was 0.01. A linear regression analysis was performed on the MD data to obtain the corresponding elastic modulus. The loading direction was varied in order to obtain the other elastic moduli. It should be noted that the above virial stress is the true stress. However, engineering stress, $\sigma$, was obtained using Equations (6) and (7).
\[ \sigma = \frac{\sigma_{\alpha\beta}}{1 + \varepsilon} \]  

(6)

\[ \varepsilon = \frac{L - L_o}{L_o} \]  

(7)

where \( L \) and \( L_o \) are the instantaneous and original length in the loading direction, respectively and \( \varepsilon \) is the engineering strain.

It should be noted that the Poisson’s effect on two orthogonal directions during uniaxial deformations for obtaining stresses was also evaluated using a linear regression analysis to obtain the in-plane Poisson’s ratio. Its value for each model was determined from the plot of longitudinal strain versus lateral strain.

Also, a planar incremental shear strain was applied to each MD models, except Si. The corresponding shear stress \( \tau_{xy} \) was computed for each time step. This simulation was performed using the NVT ensemble at 300 K and a pressure of one atmosphere at a constant engineering shear strain rate of \( 10^{-5}/\text{ps} \). A linear regression analysis was used to obtain the simulated stress-strain from the data to obtain the shear modulus \( G \). However, the Si model was assumed to be isotropic, and this \( G \) was computed from the simulated elastic modulus \( E \) and Poisson’s ratio \( \nu \) using the expression \( G = E/2(1 + \nu) \).

**Results and Discussions**

The \( \alpha \)-SiC structures, consisting of 6H SiC, 4H SiC, and 2H SiC, \( \beta \)-SiC (3C), h-BN, a-BN, and Si were created in LAMMPS. As stated before, the elastic moduli, shear moduli, and Poisson’s ratios for each model were obtained from plots of stress-strain curves using regression analysis for each model evaluated in this study. Specifically, the raw data utilized to evaluate the longitudinal elastic modulus \( (E_x) \) for 6H SiC with small (23,040 atoms) and large (329,280 atoms) models are shown in Figure 8. Slight fluctuations in the stress-strain data were observed for the small model (the plot is wider and thicker) as a result of smaller size of the system. For the larger system, these fluctuations were less significant. However, the average value of \( E_x \) obtained from three different smaller models, 543.19 GPa as shown in Table 1, was comparable to the slope obtained from the larger model \( (E_x = 609.569 \text{ GPa}) \).

![Figure 8.—Stress–strain curves for large and small 6H SiC sizes.](image)
Despite the fact that all SiC polytypes chemically consist of 50 percent carbon atoms covalently bonded with 50 percent silicon atoms, these polytypes are characterized by their stacking sequence of biatom layers of the SiC structure. The 6H SiC is composed of two-third cubic and one-third hexagonal bonds. However, the overall symmetry is hexagonal for 6H SiC, despite the cubic bonds which are present. Since this is a hexagonal material, there are five independent elastic constants required to fully characterize its elastic properties (i.e., transversely isotropic material behavior). It can be seen in Table 1 that the elastic moduli were nearly the same in the planar directions (x and y) with a noticeable difference in the direction normal to the plane (z).

Similar to $\nu_{xy}$ that is shown in Table 1, the Poisson’s ratio $\nu_{yx} = 0.2094$ was evaluated from the MD model in order to verify the reciprocity relationships, and these relationships hold true. Other planes, xz and yz were also confirmed for consistency. Experimental results from the literature (Ref. 13) are also shown in Table 1. The MD predictions compare reasonably well with the experimental data. Furthermore, each of the three realizations (samples) had similar properties, indicating that the average predicted material properties were independent of minor randomizations.

The predicted mechanical properties of the other, $\alpha$-SiC (4H SiC and 2H SiC) polytypes are shown in Table 2 and Table 3 along with available experimental data. The 4H SiC consists of an equal number of cubic and hexagonal bonds, but the overall symmetry is hexagonal. The 2H SiC (wurtzite) contains purely hexagonal bonds. The elastic moduli vary from one structure to the other as well as the degree of anisotropy. Additionally, the predicted shear moduli and Poisson’s ratios are shown in Table 2 and Table 3. These simulated properties are also compared with experimental values. As with the 6H SiC, the properties of the 4H SiC and 2H SiC structures are over-predicted. The predictions of the planar properties of the wurtzite SiC bound the results obtained from the literature using first principles and all predictions match reasonably well with the DFT data (Ref. 31). In general, no significant scatter was observed in both the 4H and 2H SiC predicted elastic constants. However, some scatter was noted in the predicted moduli for the 4H SiC. The predicted mechanical properties of $\beta$-SiC (3C) as revealed by MD simulation in comparison with other results in literature are shown in Table 4. The 3C SiC is the only form of SiC with an entirely cubic crystal lattice structure. The number “3” refers to the number of layers required for periodicity. From the data in Table 4, the 3C SiC was observed to be reasonably isotropic. The MD predictions also match closely with experimental data (Ref. 15) and DFT simulations (Ref. 5). Similar to the $\alpha$-SiC structures, no significant scatter was observed in the elastic constants for the different samples.

As an aside, MD techniques can offer significant insight into the microstructural behavior of materials where experimental data is not available on one hand, and also provide confidence in available experimental data on the other. For example, Sola et al. (Ref. 32) performed nanoindentation of Sylramic SiC fibers (specific SiC structure unknown) and obtained an $E_x$ of 315.74±39.12, 322.74±34.23, and 315.71±16.38 for three distinct Sylramic fibers. Even though it was stated that the fibers consist other impurities such as TiB$_2$ (3 percent) and B$_4$C (1 percent), the results from Table 4 suggest that the 96 percent SiC in Sylramic fibers consists predominantly of $\beta$-SiC (3C).
between the MD result and experimental data. Giving that BN has planar isotropic behavior, it can be observed for the three samples. The elastic properties for h-BN compares well with both MD and elastic properties in Table 5 that the h-BN is transversely isotropic, and the in-plane elastic modulus (E) because they are insignificant. This is due to the fact that the h-BN layers are only bonded together.

\[ \nu_{xy} = 0.2106 \]
\[ \nu_{yz} = 0.2115 \]
\[ \nu_{xz} = 0.2130 \]
\[ \nu_{zx} = 0.2117 \]
\[ \nu_{yz} = 0.1905 \]
\[ E_{xy} = 347.469 \]
\[ E_{yz} = 347.469 \]
\[ E_{xz} = 347.469 \]
\[ E = 347.469 \]
\[ G_{xy} = 347.469 \]
\[ G_{xz} = 347.469 \]
\[ G_{yz} = 347.469 \]
\[ G = 347.469 \]

The predicted elastic properties of h-BN have also been compared with available experimental data (Ref. 12) and the MD computational results (Ref. 20). These are shown in Table 5. It can be seen from the elastic properties in Table 5 that the h-BN is transversely isotropic, and the in-plane elastic modulus (E) was greater than that for any of the other SiC microstructures. No significant scatter in the properties were observed for the three samples. The elastic properties for h-BN compares well with both MD and experimental data. However, there is a significant difference in the value of the in-plane shear modulus G between the MD result and experimental data. Giving that BN has planar isotropic behavior, it can be inferred that the value of G can be estimated from \( E/2(1+\nu) \). Such an estimate is closer to the MD result than the experiment result from Reference 12. The out-of-plane properties for the h-BN are not given because they are insignificant. This is due to the fact that the h-BN layers are only bonded together through van der Waals interactions.
TABLE 6.—ELASTIC RESPONSE OF a-BN USING TERSOFF AT $\varepsilon = 10^7$/s

<table>
<thead>
<tr>
<th>Property</th>
<th>2-layered</th>
<th>4-layered</th>
<th>5-layered</th>
<th>10-layered</th>
</tr>
</thead>
<tbody>
<tr>
<td>$E_x$ (GPa)</td>
<td>49.9780</td>
<td>43.4130</td>
<td>46.3940</td>
<td>50.3710</td>
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<tr>
<td>$E_y$ (GPa)</td>
<td>52.3360</td>
<td>49.3270</td>
<td>46.7390</td>
<td>47.7820</td>
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<tr>
<td>$E_z$ (GPa)</td>
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<td>51.4950</td>
<td>56.4200</td>
<td>49.0610</td>
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<tr>
<td>$G_{xy}$ (GPa)</td>
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<td>17.3410</td>
<td>16.1800</td>
<td>20.0930</td>
</tr>
<tr>
<td>$\nu_{xy}$</td>
<td>0.3242</td>
<td>0.3067</td>
<td>0.2892</td>
<td>0.3206</td>
</tr>
<tr>
<td>$\nu_{yz}$</td>
<td>0.3290</td>
<td>0.3510</td>
<td>0.2974</td>
<td>0.3070</td>
</tr>
</tbody>
</table>

TABLE 7.—ELASTIC RESPONSE OF Si USING ReaxFF AT $\varepsilon = 10^7$/s

<table>
<thead>
<tr>
<th>Property</th>
<th>Sample 1</th>
<th>Sample 2</th>
<th>Sample 3</th>
<th>Average</th>
<th>Expt. (Ref. 33)</th>
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<td>$E_x$ (GPa)</td>
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<td>145.2360</td>
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<td>130.0000</td>
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<td>141.7790</td>
<td>143.6830</td>
<td>130.0000</td>
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<td>$G_{xy}$ (GPa)</td>
<td>54.7452</td>
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<td>54.9720</td>
<td>54.9106</td>
<td>79.6000</td>
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<tr>
<td>$G_{yz}$ (GPa)</td>
<td>55.1461</td>
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<td>79.6000</td>
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<tr>
<td>$\nu_{xy}$</td>
<td>0.3204</td>
<td>0.3207</td>
<td>0.3210</td>
<td>0.3207</td>
<td>0.2800</td>
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<tr>
<td>$\nu_{yz}$</td>
<td>0.3108</td>
<td>0.3111</td>
<td>0.3108</td>
<td>0.3109</td>
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</tbody>
</table>

The predicted a-BN mechanical properties are shown in Table 6. It can be seen that there is a tremendous reduction in both the elastic and shear moduli compared with those of the h-BN crystalline structure in Table 5. Interfacial BN coatings typically exhibit low stiffness values because they are composed predominantly of a-BN, with a very small fraction of h-BN (Refs. 8 and 9). However, the amount of h-BN can be controlled to tailor the properties of an interfacial coating. Furthermore, Table 6 shows that there is no agglomeration effect, i.e., effect of number of layer or clumping, on the mechanical properties of amorphous boron nitride. A slight difference in the elastic moduli was observed. However, this difference decreases (as expected) when the simulation volume increases. It is important to note that only one simulation was performed for each a-BN sample since the predicted material properties of the models in the present MD simulations were independent of minor randomizations.

Finally, the predicted elastic properties of crystalline Si are given in Table 7. The properties in the different directions are consistent with the isotropic nature of crystalline Si as seen in Table 7 and did not significantly vary among the three samples. As stated in Reference 33, the possible values for the elastic modulus range from 130 to 188 GPa, and those for Poisson’s ratio range from 0.048 to 0.400.

**Conclusion**

MD was used to predict the mechanical properties of the various constituent materials that compose SiC/SiC composites. This represents foundational work towards developing a multiscale modeling framework, wherein the atomic microstructure is coupled to the composite material performance, for SiC/SiC composites. The microstructures of the constituents in the SiC/SiC composite contain a variety of different phases. Crystalline $\alpha$-(6H, 4H, and 2H) and $\beta$-SiC (3C), crystalline (layered) and amorphous BN, and silicon (Si) models were constructed in LAMMPS using Tersoff potential force field, while the Reactive force field was used for Si. These structures were equilibrated to remove residual stress before they were evaluated for their mechanical properties. A total of 115 MD simulations were performed to arrive at the data reported herein. In many cases the MD predictions matched well with previously available experimental or other simulation data. It is expected that larger size and number of simulations would further improve the predicted results. The work could also be extended to infer the phase contents of the various constituents in SiC/SiC composites. Moreover, the phase content could be adjusted, through microstructural modeling, to optimize performance of the composite.
References


